

**27C128** 

## 128K (16K x 8) CMOS EPROM

## **FEATURES**

- · High speed performance
  - 120 ns access time available
- CMOS Technology for low power consumption
  - 20 mA Active current
  - 100 μA Standby current
- Factory programming available
- · Auto-insertion-compatible plastic packages
- Auto ID aids automated programming
- · Separate chip enable and output enable controls
- · High speed "express" programming algorithm
- Organized 16K x 8: JEDEC standard pinouts
  - 28-pin Dual-in-line package
  - 32-pin PLCC Package
  - 28-pin SOIC package
  - Tape and reel
- Available for the following temperature ranges:

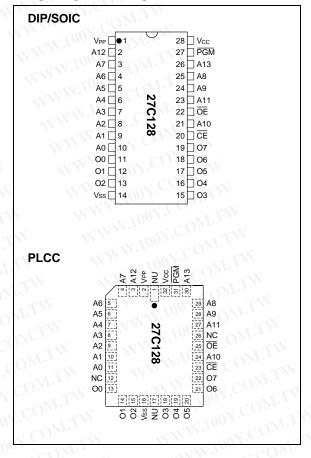
Commercial: 0°C to +70°C
 Industrial: -40°C to +85°C
 Automotive: -40°C to +125°C

## DESCRIPTION

The Microchip Technology Inc. 27C128 is a CMOS 128K bit (electrically) Programmable Read Only Memory. The device is organized as 16K words by 8 bits (16K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 120 ns. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements. A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC, SOIC, or TSOP packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages. UV erasable versions are also available.

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## PACKAGE TYPES



勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

## 1.0 ELECTRICAL CHARACTERISTICS

## 1.1 Maximum Ratings\*

Vcc and input voltages w.r.t. Vss ......-0.6V to +7.25V

VPP voltage w.r.t. Vss during
programming .....-0.6V to +14V

Voltage on A9 w.r.t. Vss ....-0.6V to +13.5V

Output voltage w.r.t. Vss ....-0.6V to Vcc +1.0V

Storage temperature ....-65°C to +150°C

Ambient temp. with power applied ....-65°C to +125°C

\*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

## TABLE 1-1: PIN FUNCTION TABLE

	(1)
Name	Function
A0-A13	Address Inputs
CE	Chip Enable
ŌE	Output Enable
PGM	Program Enable
VPP	Programming Voltage
O0 - O7	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

 $VCC = +5V (\pm 10\%)$ 

Commercial: Tamb =  $0^{\circ}$ C to  $+70^{\circ}$ C Industrial: Tamb =  $-40^{\circ}$ C to  $+85^{\circ}$ C Extended (Automotive): Tamb =  $-40^{\circ}$ C to  $+125^{\circ}$ C

MMM. TOOX.COM.	TW	WWW	Extended (Automotive): Tamb = -40°C to +125°C								
Parameter	Part*	Status	Symbol	Min.	Max.	Units	Conditions				
Input Voltages	all	Logic "1" Logic "0"	VIH VIL	2.0 -0.5	Vcc+1 0.8	V	MMM:100X:COM:				
Input Leakage	all	W - V	110	-10	10	μΑ	VIN = 0 to VCC				
Output Voltages	all	Logic "1" Logic "0"	Voh Vol	2.4	0.45	V	IOH = -400 μA IOL = 2.1 mA				
Output Leakage	all	CIV_	ILO	-10	10	μА	Vout = 0V to Vcc				
Input Capacitance	all	M.T.W	CIN	N.100	6	pF	VIN = 0V; Tamb = 25°C; f = 1 MHz				
Output Capacitance	all	OM.TW	Соит	MM.10	12	pF	Vout = 0V; Tamb = 25°C; f = 1 MHz				
Power Supply Current, Active	C I,E	TTL input TTL input	ICC1 ICC2	MM MMM MMM MMM	20 25	mA mA	$\label{eq:VCC} \begin{split} &\text{VCC} = 5.5\text{V};  \text{VPP} = \text{VCC} \\ &\frac{f = 1  \text{MHz};}{\text{OE} = \text{CE}} = \text{VIL}; \\ &\text{IOUT} = 0  \text{mA}; \\ &\text{VIL} = -0.1  \text{to}  0.8\text{V}; \\ &\text{VIH} = 2.0  \text{to}  \text{VCC}; \\ &\text{Note}  1 \end{split}$				
Power Supply Current, Standby	C I, E all	TTL input TTL input CMOS input	Icc(s)		2 3 100	mA mA μA	$\overline{CE} = Vcc \pm 0.2V$				
IPP Read Current VPP Read Voltage	all all	Read Mode Read Mode	IPP VPP	Vcc-0.7	100 Vcc	μA V	VPP = 5.5V				

<sup>\*</sup> Parts: C=Commercial Temperature Range; I, E=Industrial and Extended Temperature Ranges

Note 1: Typical active current increases .75 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

AC Testing Waveform: VIH = 2.4V and VIL = 0.45V; VOH = 2.0V VOL = 0.8V

Output Load: 1 TTL Load + 100 pF

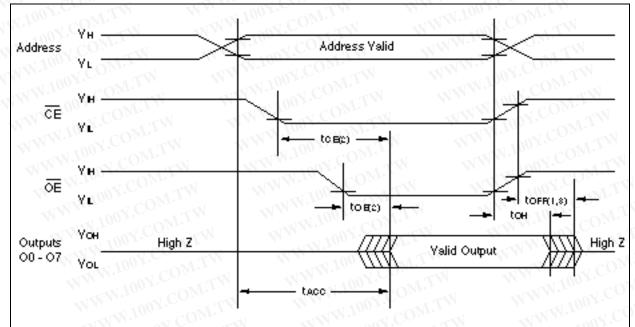
Input Rise and Fall Times: 10 ns

Ambient Temperature: Commercial: Tamb =  $0^{\circ}$ C to +70°C

Industrial: Tamb =  $-40^{\circ}$ C to  $+85^{\circ}$ C Extended (Automotive): Tamb =  $-40^{\circ}$ C to  $+125^{\circ}$ C

Parameter	Sym	27C128-12		27C128-15		27C128-17		27C128-20		27C128-25			
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Units	Conditions
Address to Output Delay	tACC	<u> </u>	120		150		170	1.100	200	M.)	250	ns	CE=OE=VIL
CE to Output Delay	tCE	100,	120		150	_	170	N-10	200	OAI	250	ns	OE=VIL
OE to Output Delay	tOE	1.400	65	<del>-</del>	70	_	70	1 <del>1/1</del> .1	75	CO)	100	ns	CE=VIL
CE or OE to O/P High Impedance	tOFF	0.0	50	0/1	50	0	50	0	55	00	60	ns	
Output Hold from Address CE or OE, whichever occurs first	ton	0	100, 100,	C <sub>0</sub>	MTI'	\ 0	- <	0	N.10	0	ON.	ns	

## FIGURE 1-1: READ WAVEFORMS



Notes: (1) topp is specified for OE or CE, whichever occurs first

- (2) OE may be delayed up to to E-to Eafter the falling edge of CE without impact on to E
- (3) This parameter is sampled and is not 100% tested.

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TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

	Y.COM.					Framb = $25^{\circ}$ C $\pm 5^{\circ}$ C P = $13.0$ V $\pm 0.25$ V
Parameter	Status	Symbol	Min	Max.	Units	Condition
Input Voltages	Logic"1" Logic"0"	VIH VIL	2.0 -0.1	Vcc+1 0.8	V	ON.TW
Input Leakage	100×.Cc	ILI.	-10	10	μΑ	VIN = 0V to VCC
Output Voltages	Logic"1" Logic"0"	Voh Vol	2.4	0.45	V	IOH = -400 μA IOL = 2.1 mA
Vcc Current, program & verify	M.100	ICC2	W-	20	mA	Note 1
VPP Current, program	MM-Inc	IPP2	TV	25 <	mA	Note 1
A9 Product Identification	MAITO	VH	11.5	12.5	V	ON CONTRACT

Note 1: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP

## TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify AC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V and Program Inhibit Modes Ambient Temperature: Tamb=25°C± 5°C VCC= 6.5V ± 0.25V, VPP = VH = 13.0V ± 0.25V										
Parameter	Symbol	Min	Max	Units	Remarks					
Address Set-Up Time	tas	2		μs	100Y.COM					
Data Set-Up Time	tDS	2	_	μs	I.I. CONT. TW					
Data Hold Time	tDH	2	_	μs	N. POOY. COND					
Address Hold Time	tah	0	V —	μs	W. LOOY. COM					
Float Delay (2)	tDF C	0	130	ns	MM.100X.COM					
Vcc Set-Up Time	tvcs	2	TV <del>V</del>	μs	MAN TOON COM					
Program Pulse Width (1)	tpw	95	105	μs	100 μs typical					
CE Set-Up Time	tces	2	TW	μs	MMM. TOON.COM					
OE Set-Up Time	toes	<b>2</b> 0	<u> </u>	μs	MMM.TOOX.CO					
VPP Set-Up Time	tvps	2	)Nr.	√μs	WWW.TOOY.C					
Data Valid from OE	toe	007.C	100	ns	MAM. TOOK.C					

Note 1: For express algorithm, initial programming width tolerance is 100  $\mu$ s  $\pm 5\%$ .

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This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

FIGURE 1-2: **PROGRAMMING WAVEFORMS (1)** Program -Address Address Stable - toe 🛶 High Z Data in Stable Data Out Yalid ton tor (2) 13.0 Y (3) 5.0 Y 6.5 Y (3) 5.0 Y ٧н YL. -to⊞-**PGM** toe (2)ŌĒ

Notes: (1) The input timing reference is 0.8Y for YL and 2.0Y for YH.

(2) to F and to E are characteristics of the device but must be accommodated by the programmer.

(3) Ycc = 6.5Y ±0.25Y, YPP = YH = 13.0Y ±0.25Y for Express algorithm.

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**TABLE 1-6: MODES** 

Operation Mode	CE	ŌĒ	PGM	VPP	А9	00 - 07
Read	VIL	VIL	VIH	Vcc	Х	Dout
Program	VIL	VIH	VIL 100	VH	Х	DIN
Program Verify	VIL	VIL	VIH	VH	X	Dout
Program Inhibit	VIH	X	X	VH	X	High Z
Standby	VIH	X	X	Vcc	X	High Z
Output Disable	VIL	VIH	VIH	Vcc	X	High Z
Identity	VIL	VIL	VIH	Vcc	VH	Identity Code

X = Don't Care

#### 1.2 Read Mode

(See Timing Diagrams and AC Characteristics) Read Mode is accessed when

- the CE pin is low to power up (enable) the chip
- the OE pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from CE to output (tCE). Data is transferred to the output after a delay from the falling edge of  $\overline{OE}$  (toe).

## 1.3 Standby Mode

The standby mode is defined when the  $\overline{CE}$  pin is high (VIH) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100  $\mu$ A.

### 1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

The OE and PGM pins are both high.

# 1.5 <u>Erase Mode (U.V. Windowed Versions)</u>

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of  $12,000\mu\text{W/cm}^2$  for approximately 20 minutes.

## 1.6 **Programming Mode**

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- a) Vcc is brought to the proper voltage,
- b) VPP is brought to the proper VH level,
- c) the  $\overline{CE}$  pin is low,
- d) the  $\overline{OE}$  pin is high, and
- e) the  $\overline{PGM}$  pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A13 and the data to be programmed is presented to pins O0-O7. When data and address are stable,  $\overline{OE}$  is high,  $\overline{CE}$  is low and a low-going pulse on the  $\overline{PGM}$  line programs that location.

## 1.7 Verify

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- a) Vcc is at the proper level,
- b) VPP is at the proper VH level,
- c) the CE line is low,
- d) the PGM line is high, and
- e) the  $\overline{OE}$  line is low.

## 1.8 Inhibit

When programming multiple devices in parallel with different data, only  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  need be under separate control to each device. By pulsing the  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  line low on a particular device in conjunction with the  $\overline{\text{PGM}}$  or  $\overline{\text{CE}}$  line low, that device will be programmed; all other devices with  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$ ); and the device is inhibited from programming.

## 1.9 Identity Mode

In this mode specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The  $\overline{\text{CE}}$  and  $\overline{\text{OE}}$  lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin →	Input	Output										
Identity	Α0	0 7	0	O 5	O 4	O 3	0 2	0 1	0	H e x		
Manufacturer Device Type*	VIL VIH	0	0	1 0	0	1 0	0	0	1	29 83		

<sup>\*</sup> Code subject to change

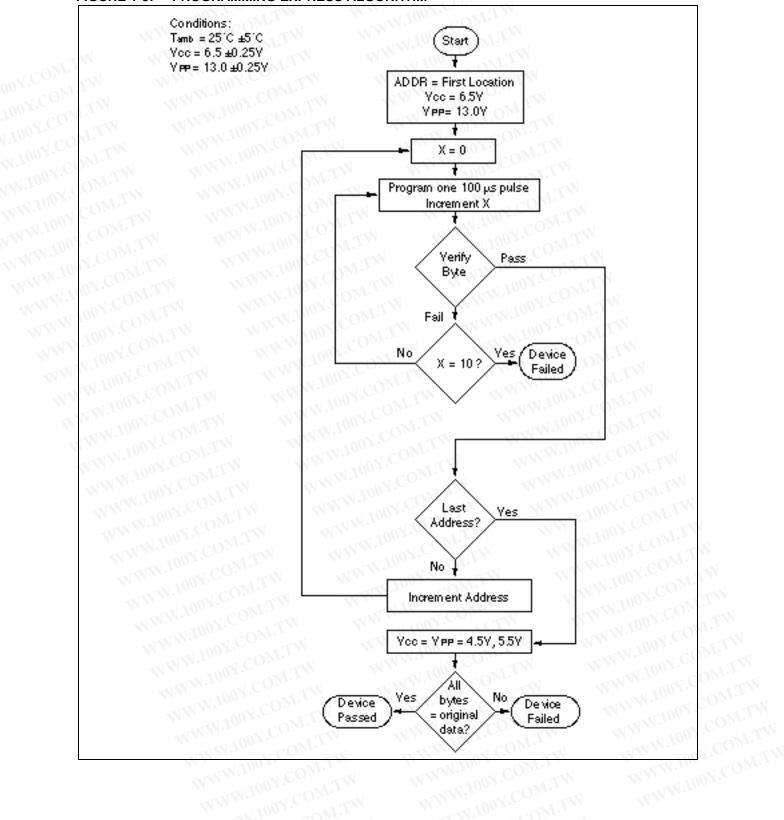
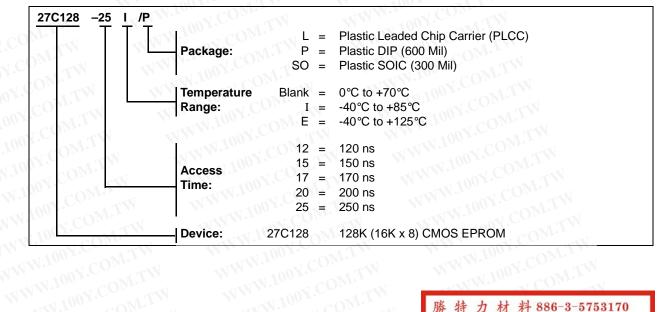


FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM

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## 27C128 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.



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